

# T1CHAL16L8-35C, T1CHAL16R4-35C, T1CHAL16R6-35C, T1CHAL16R8-35C HIGH-SPEED HAL® CIRCUITS

D2972, MARCH 1987—REVISED DECEMBER 1987

- Mask-Programmed Version of 20-Pin PAL® Family
- Virtually Zero Standby Power
- 35-ns Maximum Propagation Delay
- HC, HCT, and TTL Compatible
- Choice of 20-Pin DIP, 20-Pin SO (Small Outline) or 20-Pin PLCC Packages
- Low-Power Replacement for 20-Pin 'A' PAL® Devices
- Dependable Texas Instruments Quality and Reliability

DEVICE	INPUTS	3-STATE O OUTPUTS	REGISTERED OUTPUTS	I/O PORTS
'HAL16L8	10	2	0	6
'HAL16R4	8	0	4 (3-state)	4
'HAL16R6	8	0	6 (3-state)	2
'HAL16R8	8	0	8 (3-state)	0

## description

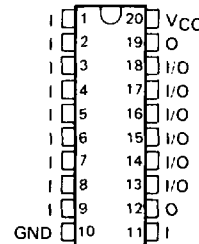
These high-speed CMOS Hard Array Logic (HAL®) circuits are mask-programmed versions of the 20-pin PAL® devices. They provide reliable, high-speed, low-power substitutes for conventional TTL and HCT logic. They are also compatible with HC logic over  $V_{CC}$  range of 4.5 volts to 5.5 volts.

This family of CMOS HAL® circuits provide the flexibility of using integrated circuits with virtually zero standby power and lower operating power than those currently achieved by bipolar PALs. Prototyping can be done using standard PAL® devices before converting to CMOS HAL® circuits for production.

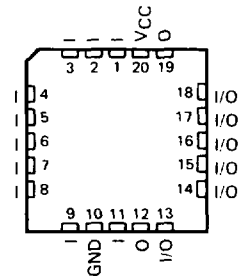
The T1CHAL16' circuits have internal electrostatic discharge (ESD) protection circuits and have been classified with a 2000-volt ESD rating tested under MIL-STD-883B, Method 3015.1. However, care should be exercised in handling these devices as exposure to ESD may result in a degradation of the device parametric performance.

The C suffix designates commercial-temperature circuits that are characterized for operation from 0°C to 75°C.

T1CHAL16L8  
C SUFFIX . . . DW OR N PACKAGE  
(TOP VIEW)



T1CHAL16L8  
C SUFFIX . . . FN PACKAGE  
(TOP VIEW)



2

Data Sheets

PAL and HAL are registered trademarks of Monolithic Memories Inc.

PRODUCTION DATA documents contain information current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

TEXAS  
INSTRUMENTS

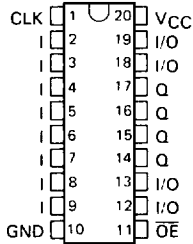
POST OFFICE BOX 655012 • DALLAS, TEXAS 75265

Copyright © 1987, Texas Instruments Incorporated

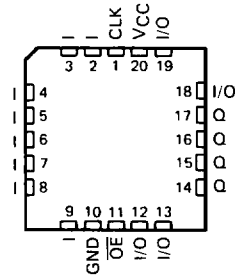
2-229

**TICHAL16R4-35C, TICHAL16R6-35C, TICHAL16R8-35C  
HIGH-SPEED CMOS *HAL*® CIRCUITS**

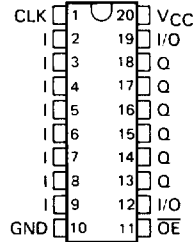
**TICHAL16R4**  
C SUFFIX . . . DW OR N PACKAGE  
(TOP VIEW)



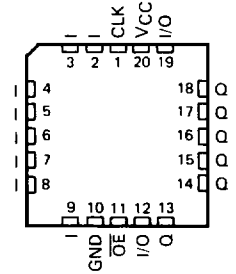
**TICHAL16R4**  
C SUFFIX . . . FN PACKAGE  
(TOP VIEW)



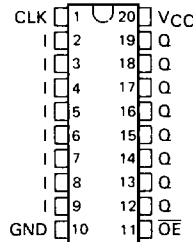
**TICHAL16R6**  
C SUFFIX . . . DW OR N PACKAGE  
(TOP VIEW)



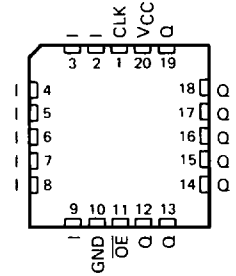
**TICHAL16R6**  
C SUFFIX . . . FN PACKAGE  
(TOP VIEW)



**TICHAL16R8**  
C SUFFIX . . . DW OR N PACKAGE  
(TOP VIEW)



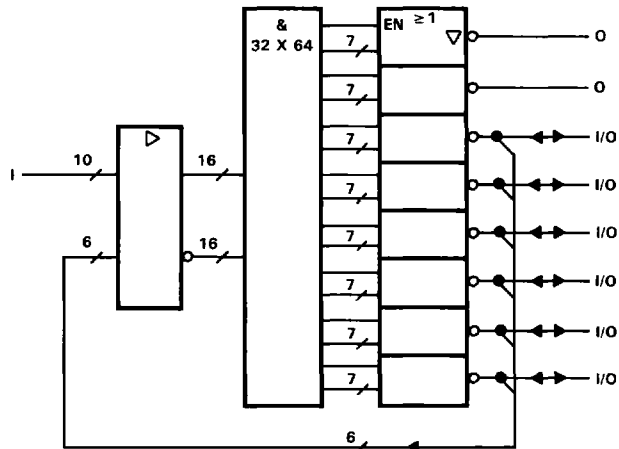
**TICHAL16R8**  
C SUFFIX . . . FN PACKAGE  
(TOP VIEW)



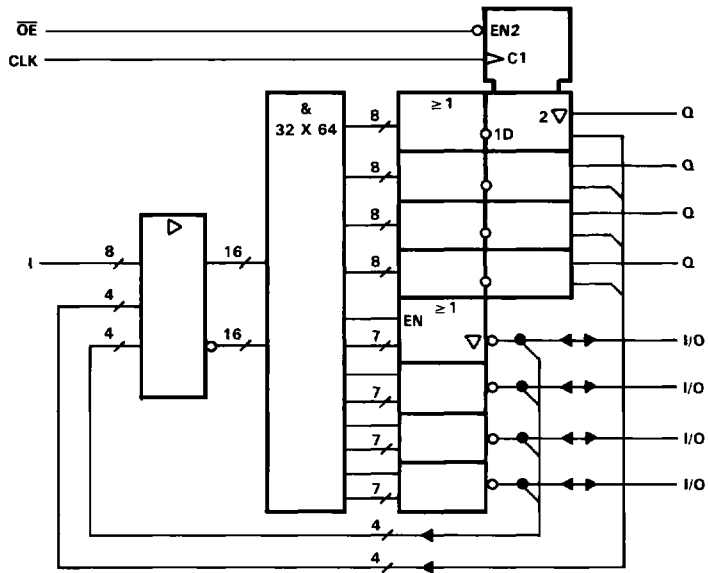
**TICHAL16L8-35C, TICHAL16R4-35C  
HIGH-SPEED CMOS HAL® CIRCUITS**

functional block diagrams (positive logic)

TICHAL16L8



TICHAL16R4



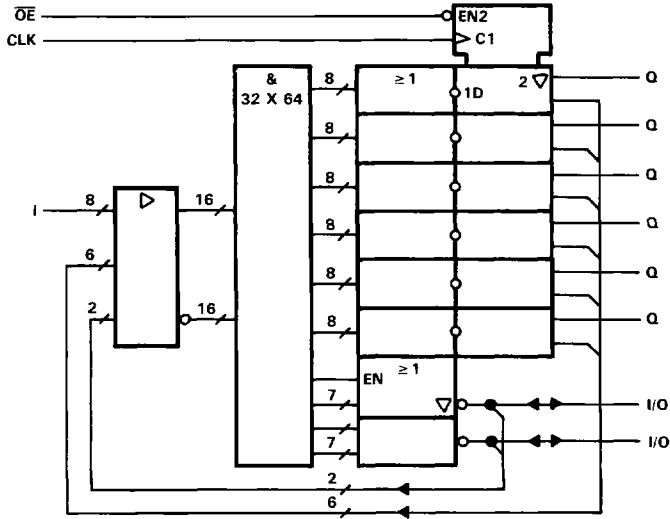
**2**  
Data Sheets

**TICHAL16R6-35C, TICHAL16R8-35C  
HIGH-SPEED CMOS HAL® CIRCUITS**

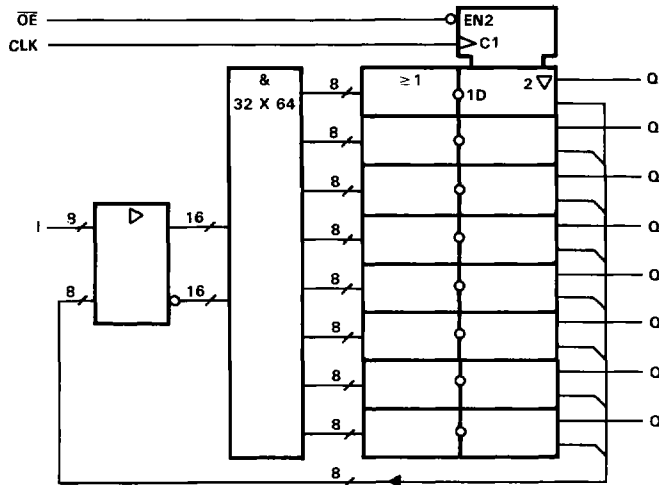
functional block diagrams (positive logic)

**2**  
Data Sheets

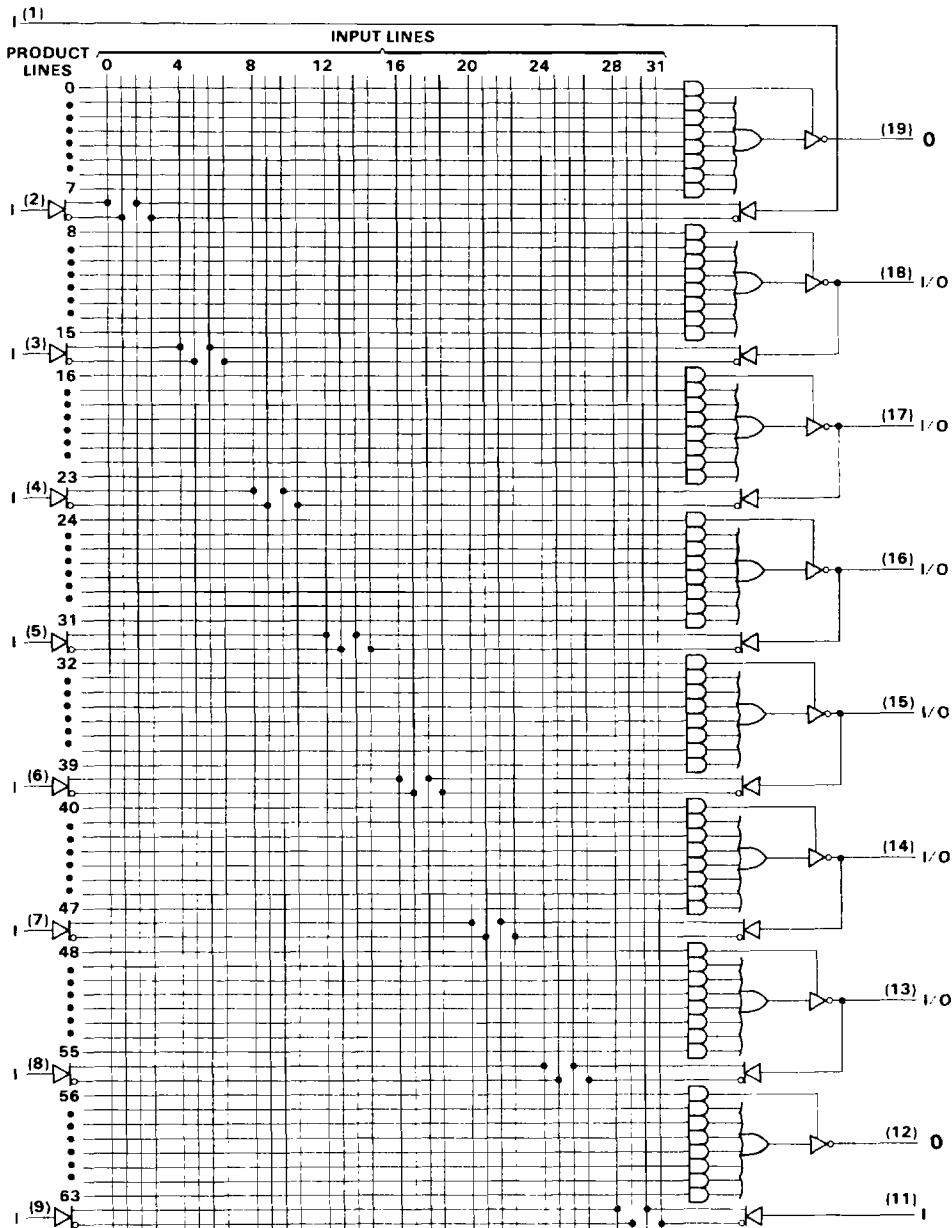
TICHAL16R6



TICHAL16R8



logic diagram (positive logic)

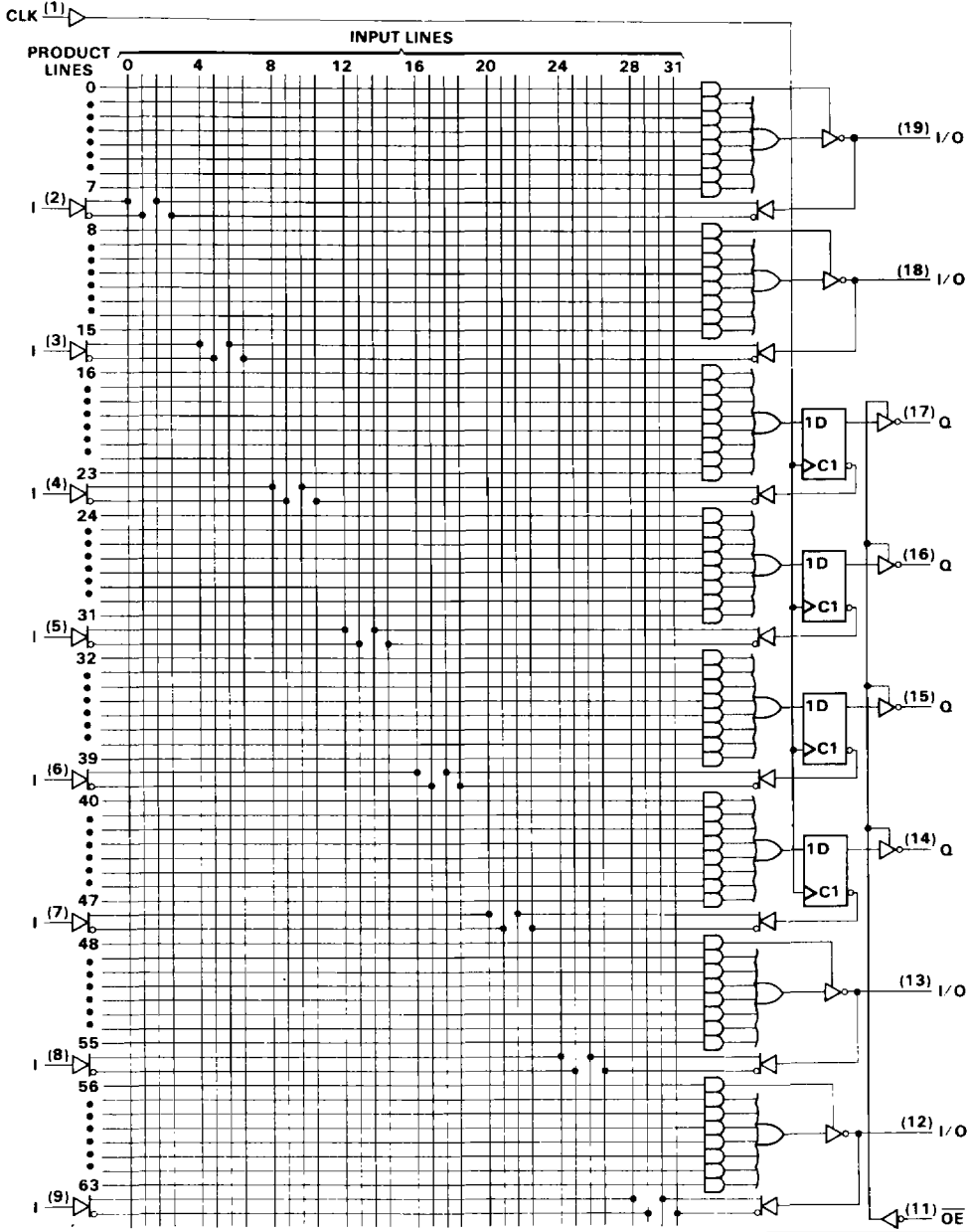


2

Data Sheets

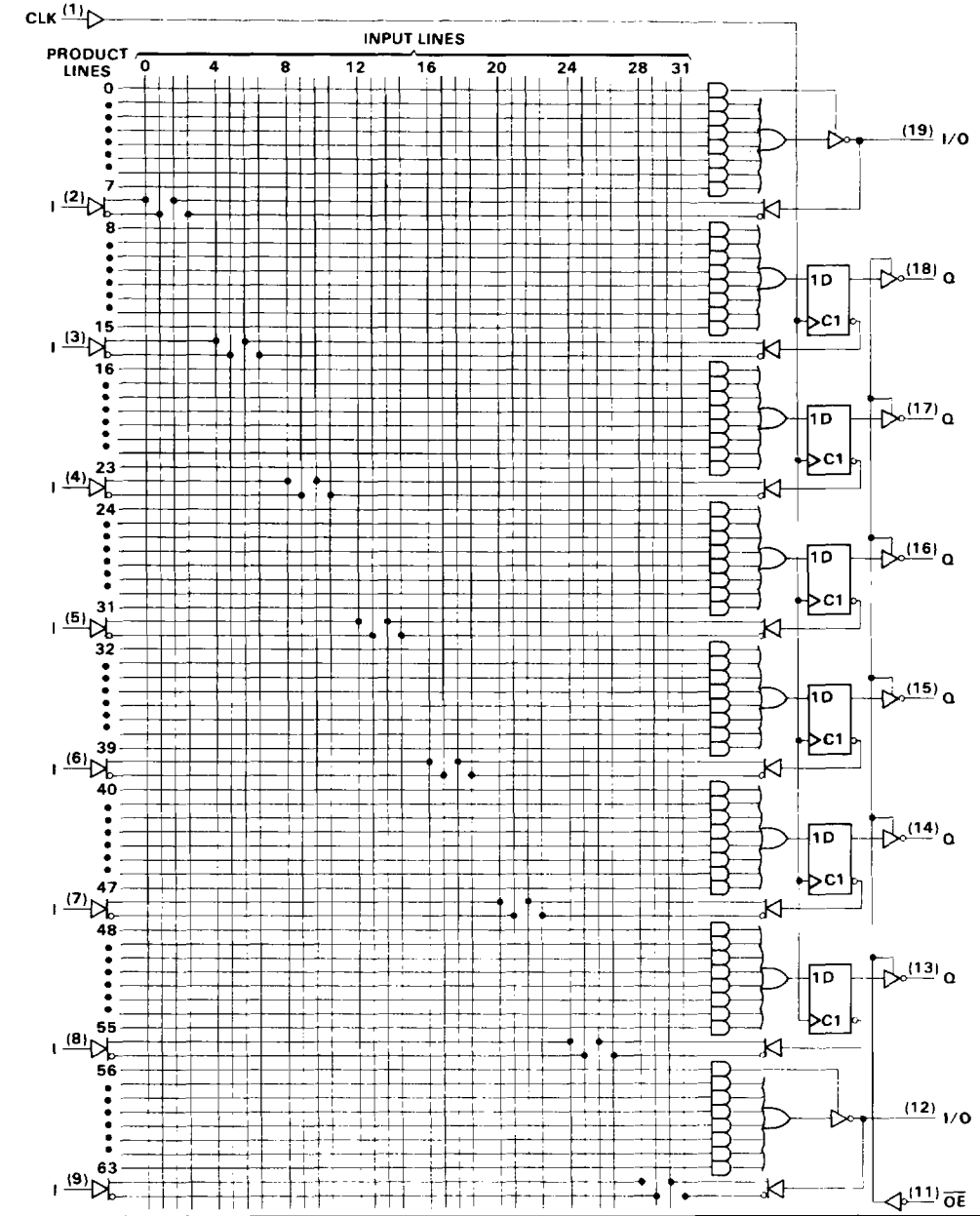
**TICHAL16R4-35C**  
**HIGH-SPEED CMOS HAL® CIRCUITS**

logic diagram (positive logic)



**2**  
**Data Sheets**

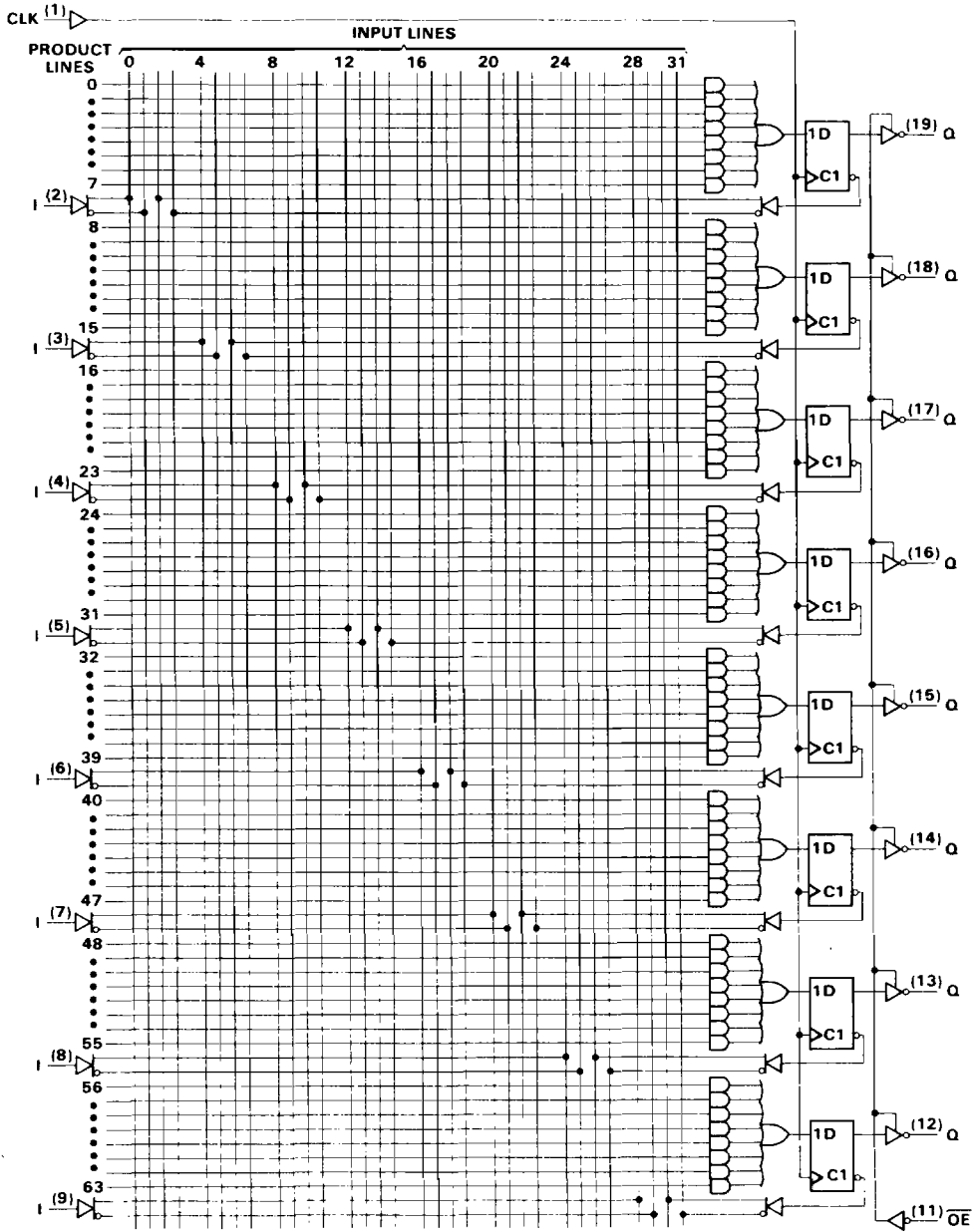
logic diagram (positive logic)



2  
Data Sheets

**TICHAL16R8-35C**  
**HIGH-SPEED CMOS HAL® CIRCUITS**

logic diagram (positive logic)



**T1CHAL16L8-35C, T1CHAL16R4-35C, T1CHAL16R6-35C, T1CHAL16R8-35C  
HIGH-SPEED CMOS HAL® CIRCUITS**

**absolute maximum ratings over operating free-air temperature range (unless otherwise noted)**

Supply voltage range, $V_{CC}$ .....	-0.5 V to 7 V
Input voltage range, $V_I$ .....	-0.5 V to $V_{CC} + 0.5$ V
Input clamp current, $I_{IK}$ ( $V_I < 0$ or $V_I > V_{CC}$ ) .....	$\pm 20$ mA
Output clamp current, $I_{OK}$ ( $V_O < 0$ or $V_O > V_{CC}$ ) .....	$\pm 20$ mA
Continuous output current, $I_O$ ( $V_O = 0$ to $V_{CC}$ ) .....	$\pm 35$ mA
Continuous current through $V_{CC}$ pin .....	70 mA
Continuous current through GND pin .....	-200 mA
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds .....	260°C
Operating free-air temperature range .....	0°C to 75°C
Storage temperature range .....	-65°C to 150°C

**recommended operating conditions**

		C-SUFFIX			UNIT
		MIN	NOM	MAX	
$V_{CC}$	Supply voltage	4.5		5.5	V
$V_{IH}$	High-level input voltage	2			V
$V_{IL}$	Low-level input voltage			0.8	V
$t_w$	Pulse duration	Clock high		20	ns
		Clock low		20	
$t_{su}$	Setup time, input or feedback before CLK1	30			ns
$t_h$	Hold time, input or feedback after CLK1	0			ns
$T_A$	Operating free-air temperature range	0		75	°C

**2**

**Data Sheets**

**TICHAL16L8-35C, TICHAL16R4-35C, TICHAL16R6-35C, TICHAL16R8-35C**  
**HIGH-SPEED CMOS HAL® CIRCUITS**

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	C-SUFFIX			UNIT
		MIN	TYP†	MAX	
V <sub>OH</sub> High-level output voltage	V <sub>CC</sub> = 4.5 V, I <sub>OH</sub> = -6 mA	3.76			V
V <sub>OL</sub> Low-level output voltage	V <sub>CC</sub> = 4.5 V, I <sub>OL</sub> = 24 mA	0.4			V
I <sub>OZH</sub> Off-state output current with high-level voltage applied	V <sub>CC</sub> = 5.5 V, V <sub>O</sub> = V <sub>CC</sub>	10			μA
I <sub>OZL</sub> Off-state output current with low-level voltage applied	V <sub>CC</sub> = 5.5 V, V <sub>O</sub> = 0	-10			μA
I <sub>IH</sub> High-level input current	V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = V <sub>CC</sub>	1			μA
I <sub>IL</sub> Low-level input current	V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 0	-1			μA
I <sub>CC</sub> Standby supply current	V <sub>CC</sub> = 5.5 V, I <sub>O</sub> = 0	100			μA
I <sub>CC</sub> Operating supply current	V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 0 or V <sub>CC</sub> , f ≥ 1 MHz, I <sub>O</sub> = 0	2			mA/MHz
ΔI <sub>CC</sub> ‡ Change in supply current	V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 0.5 V or 2.4 V, Other inputs at 0 or V <sub>CC</sub>	1.4 3			mA
C <sub>i</sub> Input capacitance	T <sub>A</sub> = 25°C, f = 1 MHz	10			pF
C <sub>o</sub> Output capacitance	T <sub>A</sub> = 25°C, f = 1 MHz	10			pF

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	C-SUFFIX			UNIT
				MIN	TYP†	MAX	
f <sub>max</sub> §		with feedback	R <sub>1</sub> = 200 Ω, R <sub>2</sub> = 390 Ω, C <sub>L</sub> = 50 pF	18			MHz
		without feedback		25			
t <sub>pd</sub>	I, I/O, or feedback	0 or I/O		18 35			ns
t <sub>pd</sub>	CLK†	Q		10 25			ns
t <sub>en</sub>	OE‡	Q		12 25			ns
t <sub>dis</sub>	OE‡	Q		12 25			ns
t <sub>en</sub>	I or I/O	0 or I/O		14 35			ns
t <sub>dis</sub>	I or I/O	0 or I/O		16 35			ns

† All typical values are V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C.

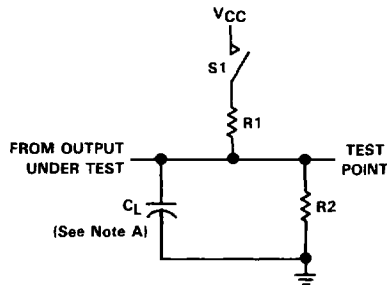
‡ This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 or V<sub>CC</sub>.

$$§ f_{max} \text{ (with feedback)} = \frac{1}{t_{su} + t_{pd} \text{ (CLK to Q)}}; f_{max} \text{ (without feedback)} = \frac{1}{t_{w(\text{high})} + t_{w(\text{low})}}$$

2

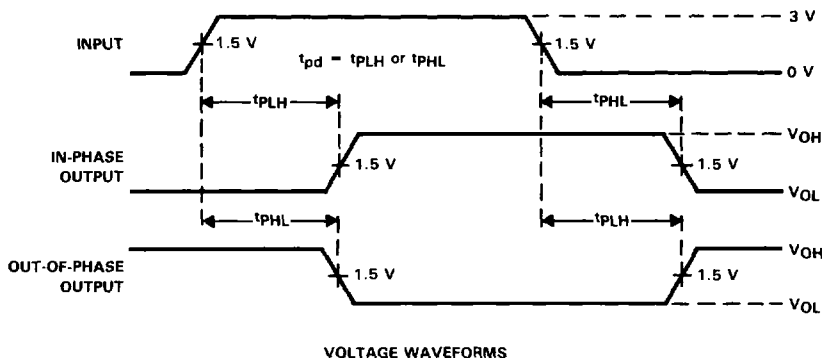
Data Sheets

PARAMETER MEASUREMENT INFORMATION



- NOTES: A.  $C_L$  = includes probe and jig capacitance.  
B. When measuring propagation times of 3-state outputs, S1 is closed.

FIGURE 1. LOAD CIRCUIT FOR THREE-STATE OUTPUTS

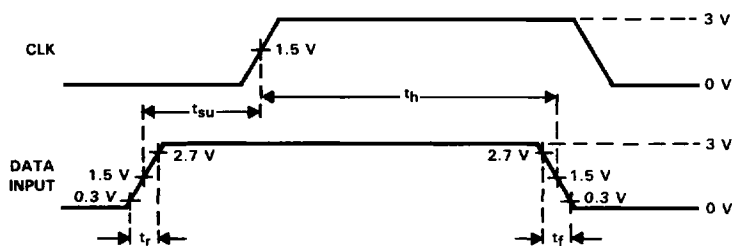


- NOTES: A. When measuring propagation times of 3-state outputs, S1 is closed.  
B. All input pulses are supplied by generators having the following characteristics:  $PRR \leq 1$  MHz,  $Z_o = 50 \Omega$ ,  $t_r = 6$  ns.

FIGURE 2. PROPAGATION DELAY TIMES, OUTPUT RISE AND FALL TIMES

**TICHAL16L8-35C, TICHAL16R4-35C, TICHAL16R6-35C, TICHAL16R8-35C**  
**HIGH-SPEED CMOS HAL® CIRCUITS**

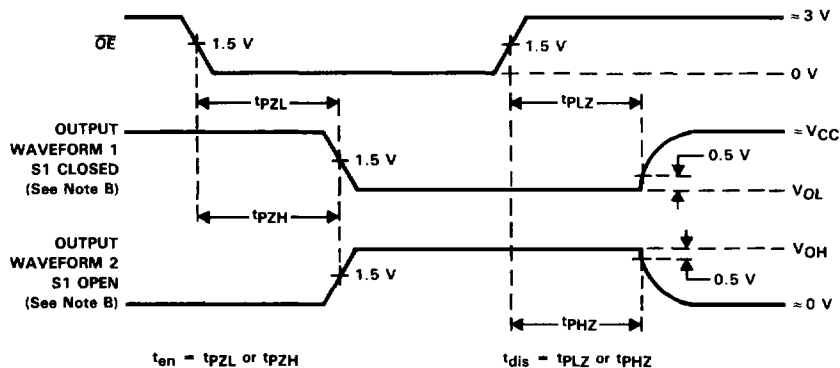
**PARAMETER MEASUREMENT INFORMATION**



**VOLTAGE WAVEFORMS**

NOTE: Phase relationship between waveforms was chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_0 = t_r = 6$  ns,  $t_f = 6$  ns.

**FIGURE 3. SETUP AND HOLD TIMES, AND INPUT RISE AND FALL TIMES**



**VOLTAGE WAVEFORMS**

NOTES: A. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_0 = 50 \Omega$ ,  $t_r = 6$  ns,  $t_f = 6$  ns.  
 B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.

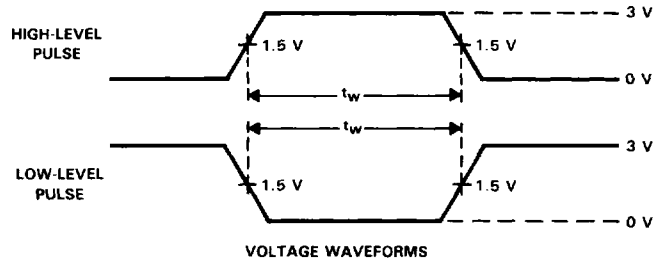
**FIGURE 4. ENABLE AND DISABLE TIMES FOR 3-STATE OUTPUTS**

2

Data Sheets

TICHAL16L8-35C, TICHAL16R4-35C, TICHAL16R6-35C, TICHAL16R8-35C  
HIGH-SPEED CMOS HAL® CIRCUITS

PARAMETER MEASUREMENT INFORMATION



NOTES: A. All input pulses are supplied by generators having the following characteristics:  $PRR \leq 1$  MHz,  $Z_o = 50 \Omega$ ,  $t_r = 6$  ns.  
B. For clock inputs,  $f_{max}$  is measured with input duty cycle = 50%.

FIGURE 5. PULSE DURATIONS

2

Data Sheets